

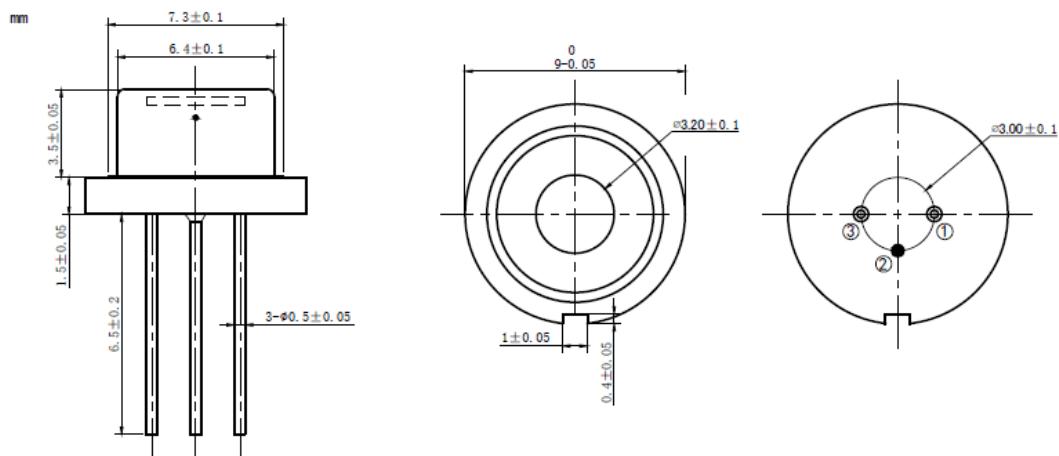
808nm~810nm 1W Laser Diodes | TO5 9mm Package| Built-in PD| Square Beam Optional

808nm 1000mW High Power LD with Photodiode | FAC Lens Optional

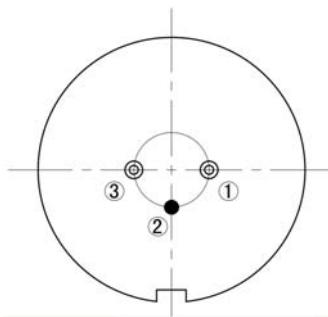
RWSLD-808-001-2-PD

808nm Laser Diode 1W/TO5			
Reverse Voltage	V_r	2.0	V
Operating Temperature	T_{op}	0~+40	°C
Storage Temperature	T_{stg}	-40~+85	°C
Lead soldering temperature (10 sec.)	T_{ls}	260	°C
Features:	<ul style="list-style-type: none"> ● 808nm ● TO5 Package ● Built-in PD ● Square Beam Optional 		
Applications:	<ul style="list-style-type: none"> ● Medical Laser Treatment ● Laser Indicator ● Others 		
Specifications	RWSLD-808-001-2-PD		
	Min	Type	Max
Center Wavelength@25°C	±3nm	808nm	±10nm
Spectral Width (FWHM)	----	2.5nm	----
Output Power	----	1W	----
Recommended Operating Temperature	25°C		
Beam Divergence (FWHM)	----	38° \perp x 10°//	40° \perp x 12°//
Temperature Coefficient of Wavelength	----	0.3nm / °C	----
Slope Efficiency	----	1.1W/A	----
Threshold Current (Typ.)	----	0.2A	----
Operating Current (Typ.)	----	1.2A	----
Operating Voltage	----	2.2V	----
Package Style	TO5		
FAC Lens	Optional		

TO5 Package View



PIN Bottom View:



1	LD(-)
2	LD(+) & PD(-)
3	PD(+)

Electrically shorten LD module and store in non-extreme conditions.

Suggest using the constant current power supply.

